GENERAL DESCRIPTION

The S100-12 is designed for common emitter HF, SSB applications from a 12 volt supply. It may be operated Class A, AB or C. The device has emitter ballasting for ruggedness and reliability.

COMMUNICATIONS HF

100 WATTS - 12.5 VOLTS

1.5-30 MHz

100-12

ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation @ 25 C Case Temperature

250 W

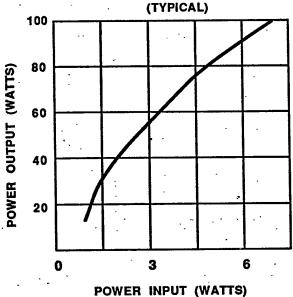
Maximum Voltage and Current

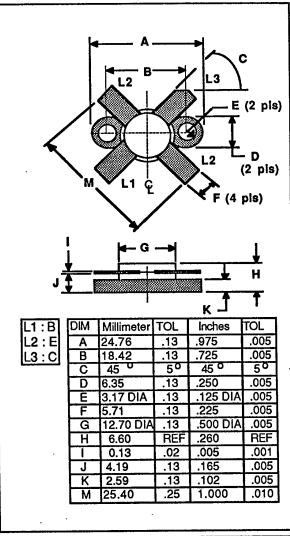
Collector to Emitter Voltage BVces 3.6 V Emitter to Base Voltage BVebo 4.0 V Collector Current 50 A k

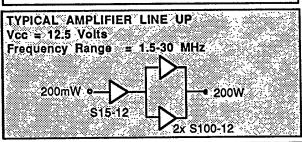
Maximum Temperatures Storage Temperature Operating Temperature

-65 to +150 °C +200 °C

POWER OUTPUT VS POWER INPUT







Phone (408) 294-4200, TWX (910) 338-2172 REV A AUG 1987 490 Race Street, San Jose, CA 95126 Ewenny Rd., Bridgend, Mid Glamorgan, CF31 3LQ, United Kingdom, Phone (0656) 68021

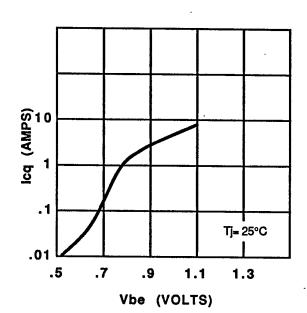
Printed in USA

S100-12-2

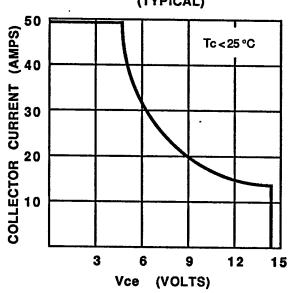
ELECTRICAL CHARACTERISTICS

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Pout	Power Output	f= 1.5 - 30MHz	100			Watts
Pin	Power Input	At Rated Power Out, Vc=12.5V	-		8.5	Watts
Pg	Power Gain		10.7	-		dB
BVebo	Voltage - Emitter to Base	le= 10mA	3.5			Volts
BVces	Voltage - Collector to Base	Ic= 100mA	36			Volts
BVceo	Voltage - Collector to Emitter	Ic= 100mA	16			Volts
IMD	Intermodulation Distortion Level				-30	dBc
VSWR	Load Mismatch Tolerance		-		30:1	-
ης	Collector Efficiency	At Rated Power Out		65		%
Ices	Collector to Base Cutoff Current	Vcb=15V	.=.		50	mA
Ccb	Capacitance- Collector to Base	Vcb=12.5V, f=1MHz		400		pF
h _{FE}	DC-Current Gain	Vce=5V, Ic=1A	10			
θјс	Thermal Resistance				0.7	°C/W



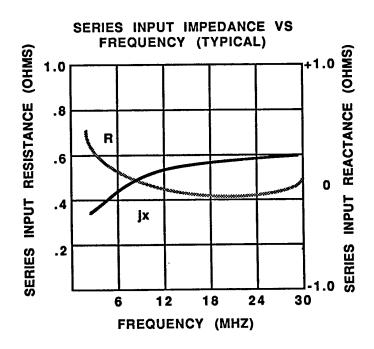


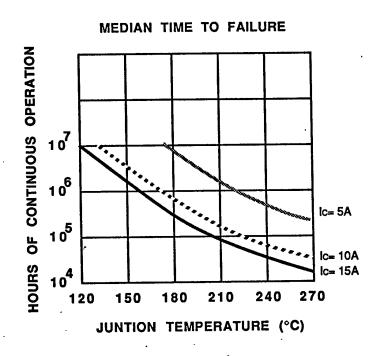
DC SAFE OPERATING AREA (TYPICAL)



SPECIFICATIONS MAY BE SUBJECT TO CHANGE WITHOUT NOTICE

S100-12-3





SPECIFICATIONS MAY BE SUBJECT TO CHANGE WITHOUT NOTICE

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